



Title: NONVOLATILE MEMORY ON SOI AND COMPOUND
SEMICONDUCTOR SUBSTRATES AND METHOD OF
FABRICATION

Inventor(s): Andrew J. WALKER et al.

Appl. No.: 09/927,642

Client/Matter No.: 035905/0103

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FIG. 1

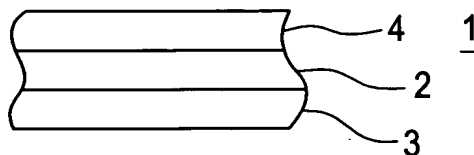


FIG. 2A

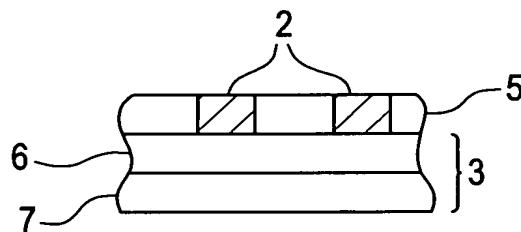


FIG. 2B

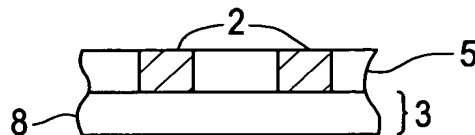
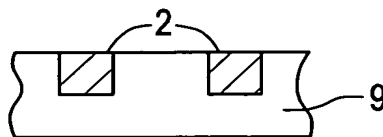


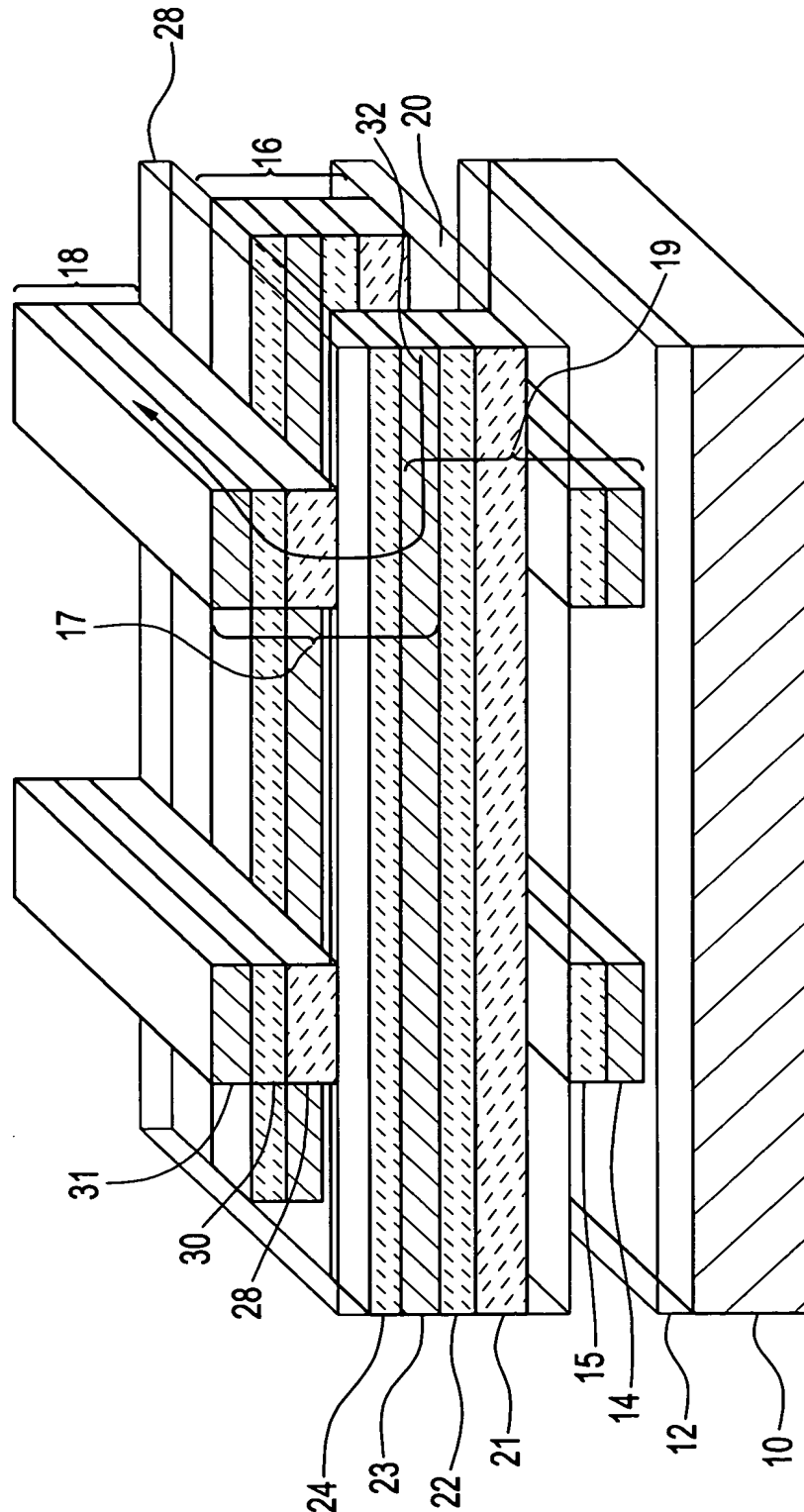
FIG. 3





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FIG. 4A





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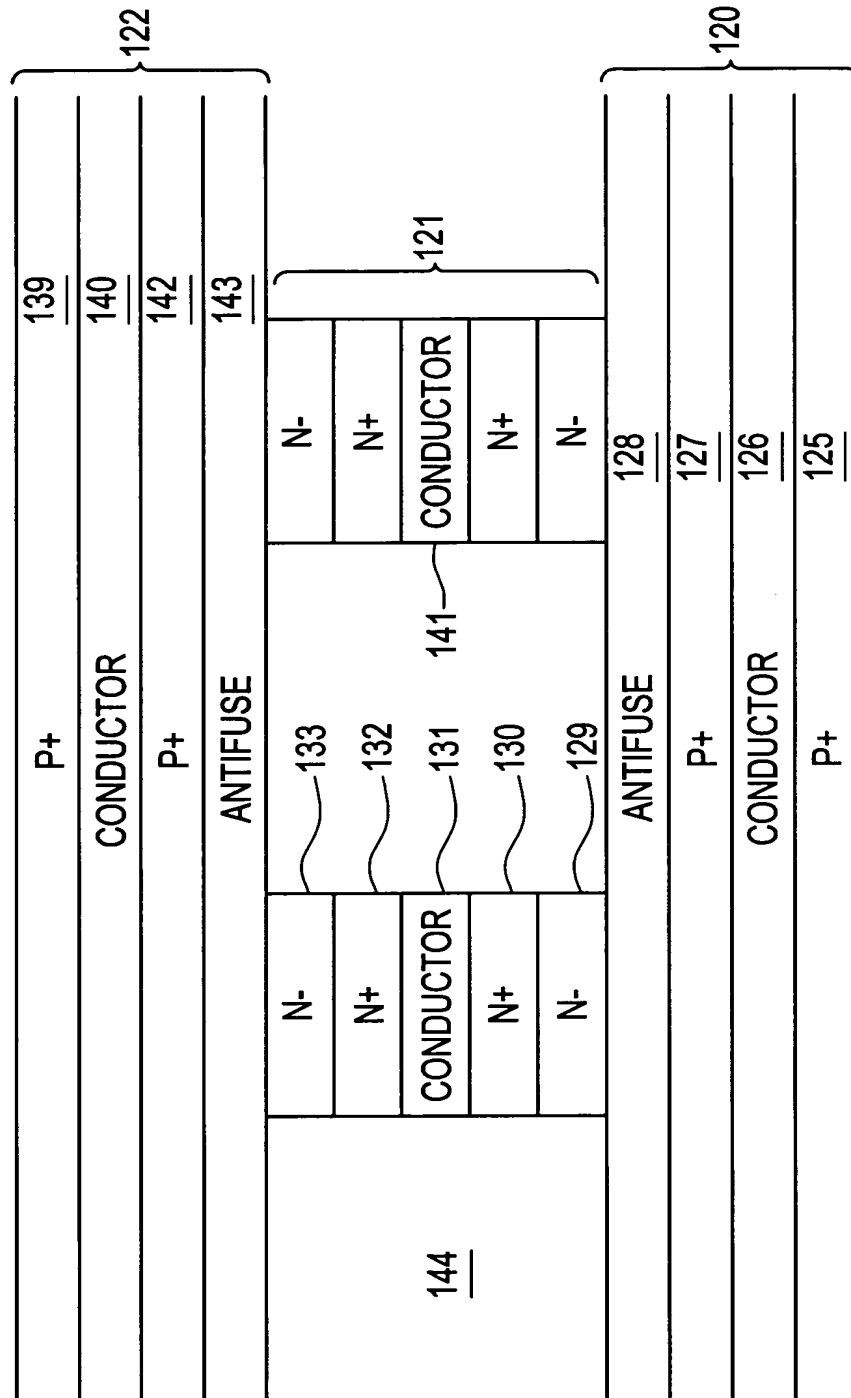
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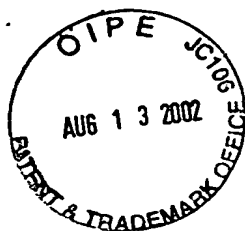
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FIG. 4B





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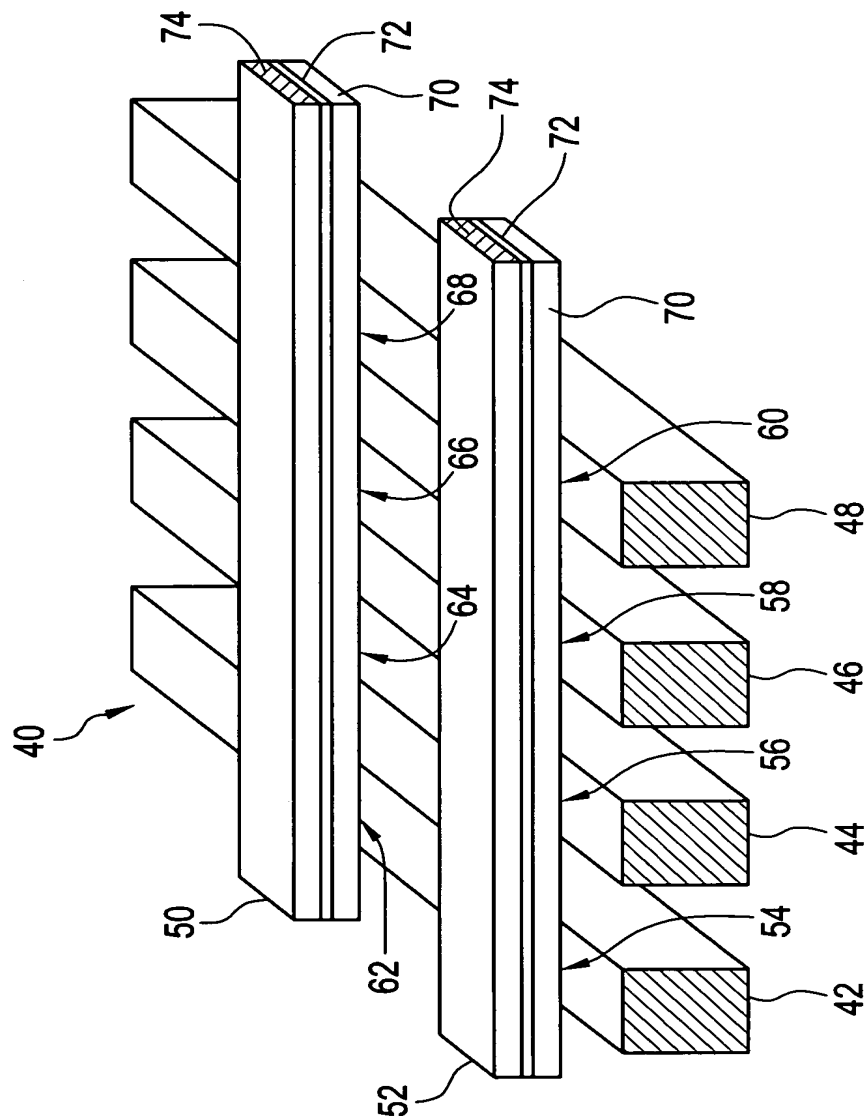
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FIG. 5





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FIG. 6

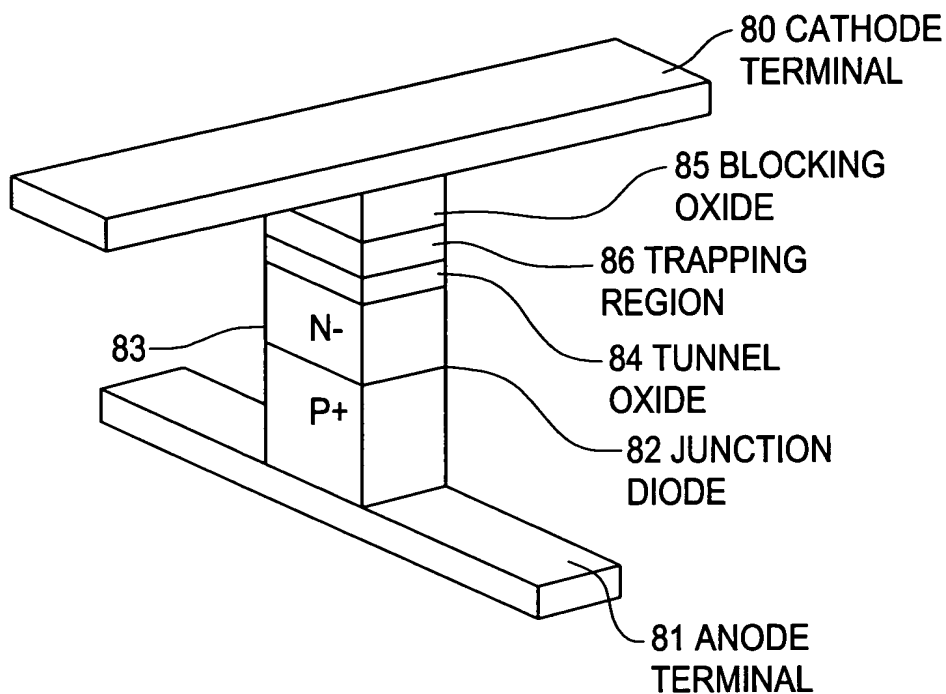
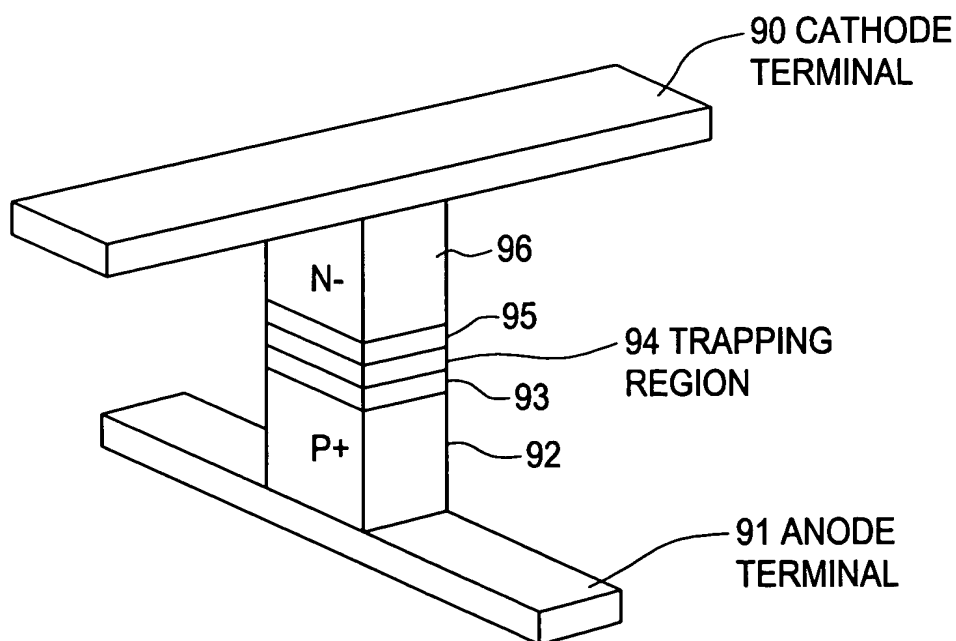
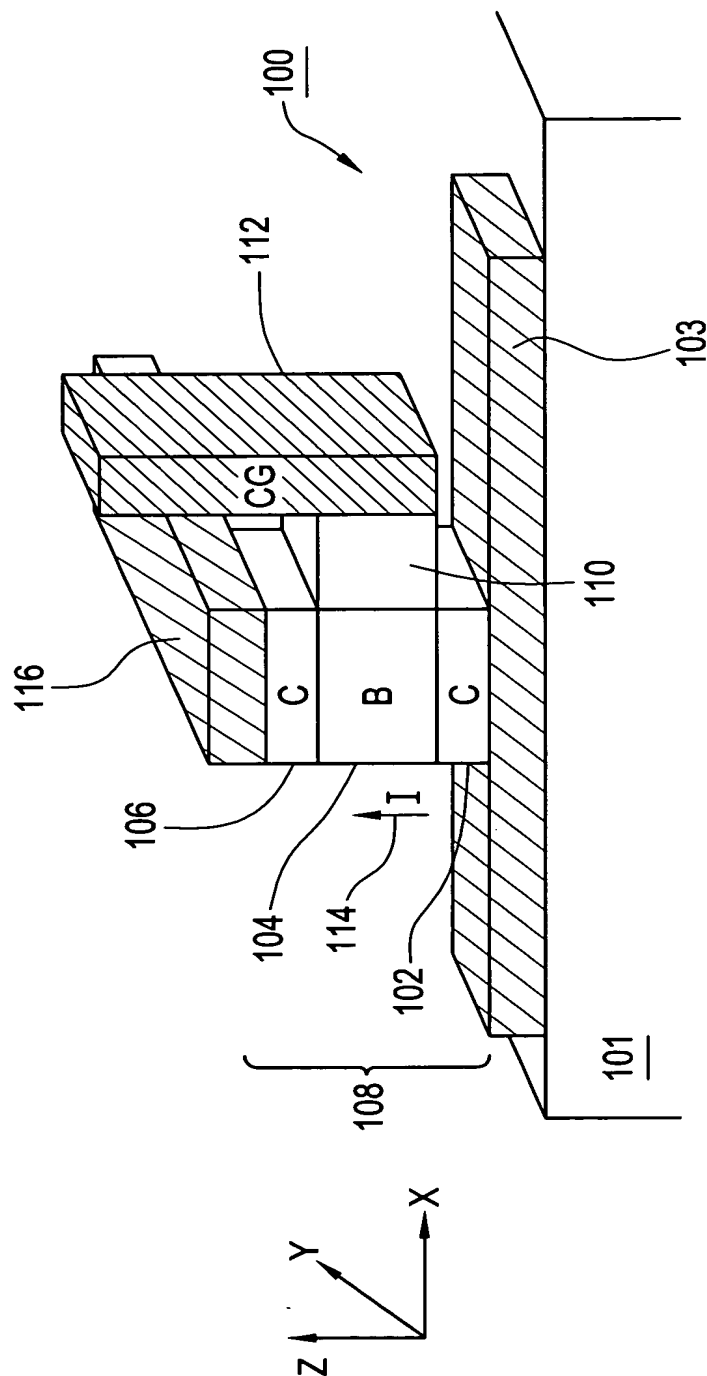


FIG. 7



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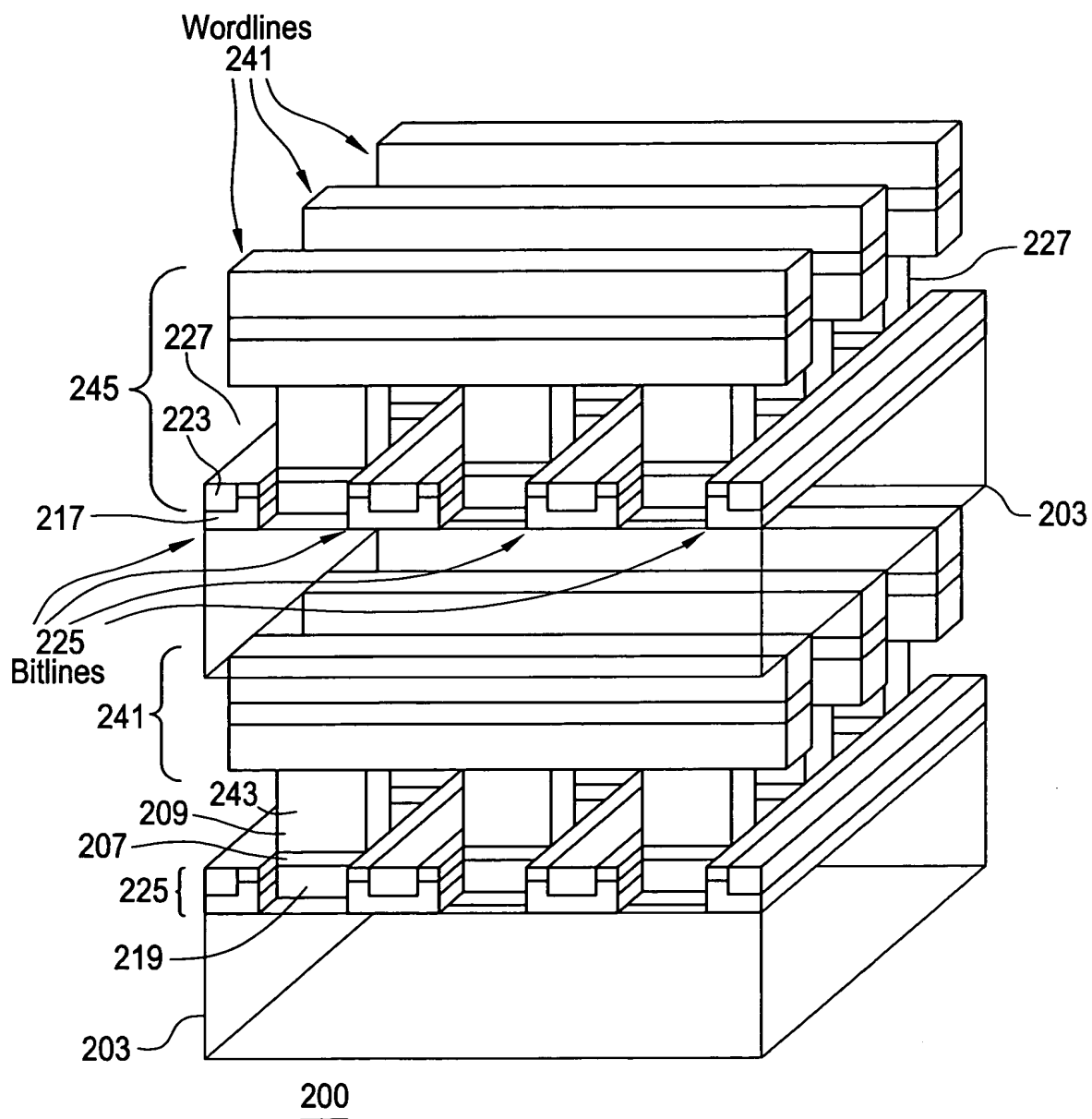
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FIG. 9





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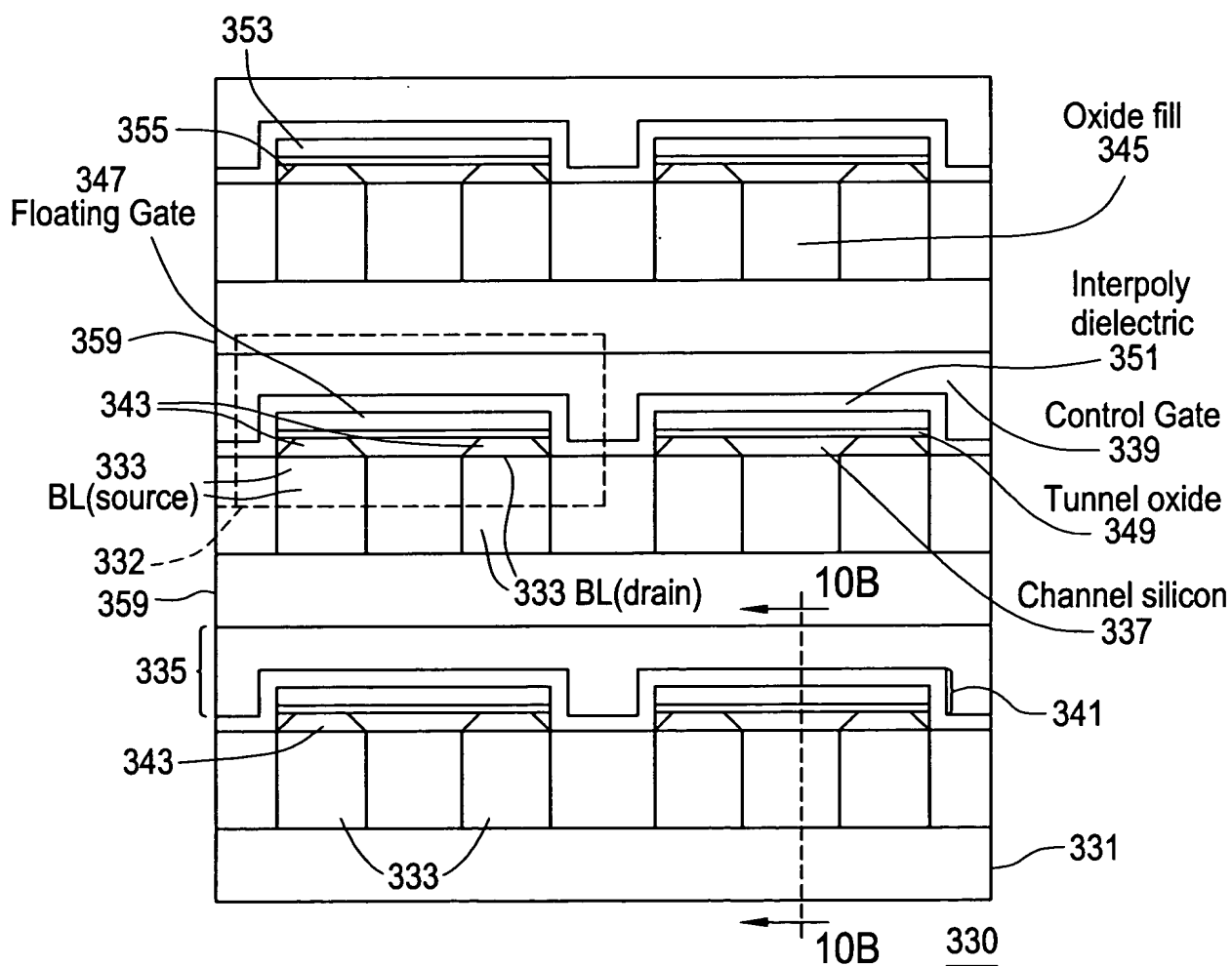
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FIG. 10A



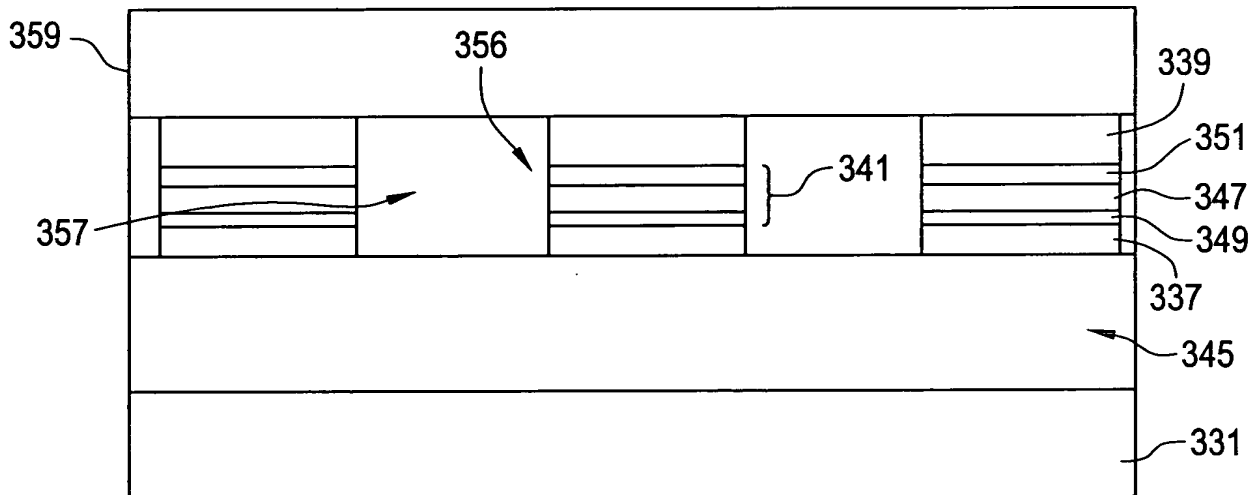


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FIG. 10B





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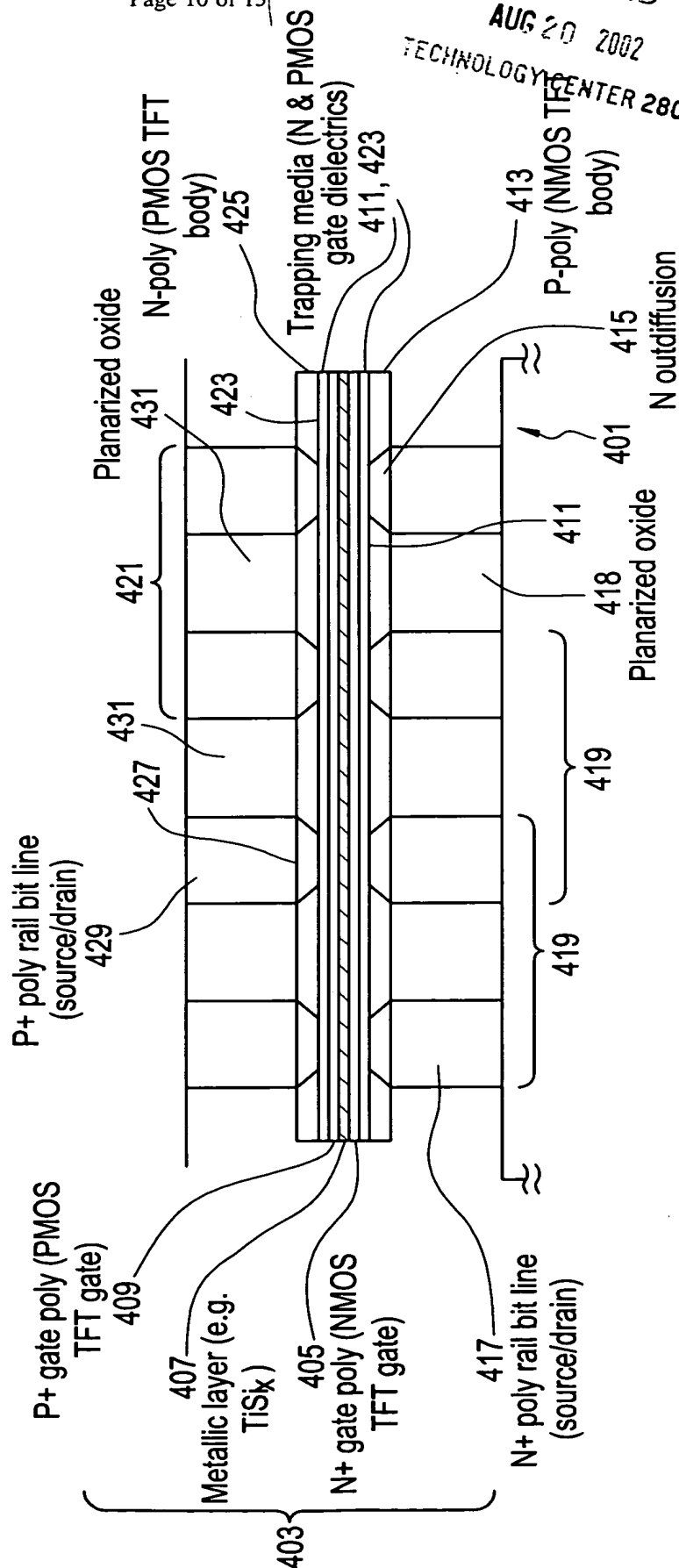
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FIG. 11

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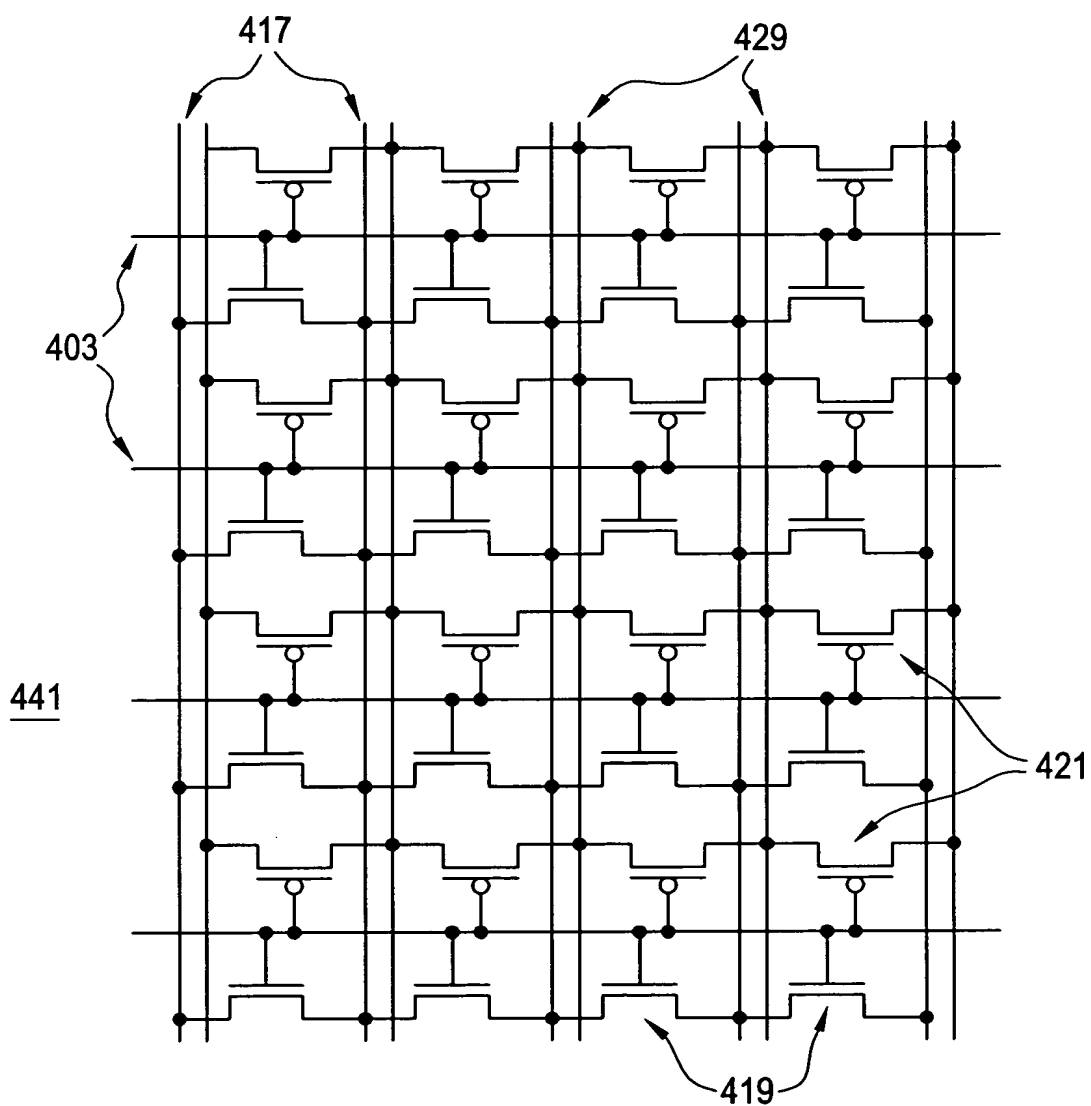
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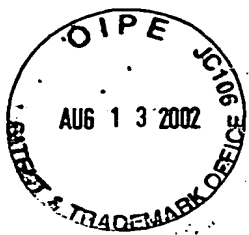
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FIG. 12



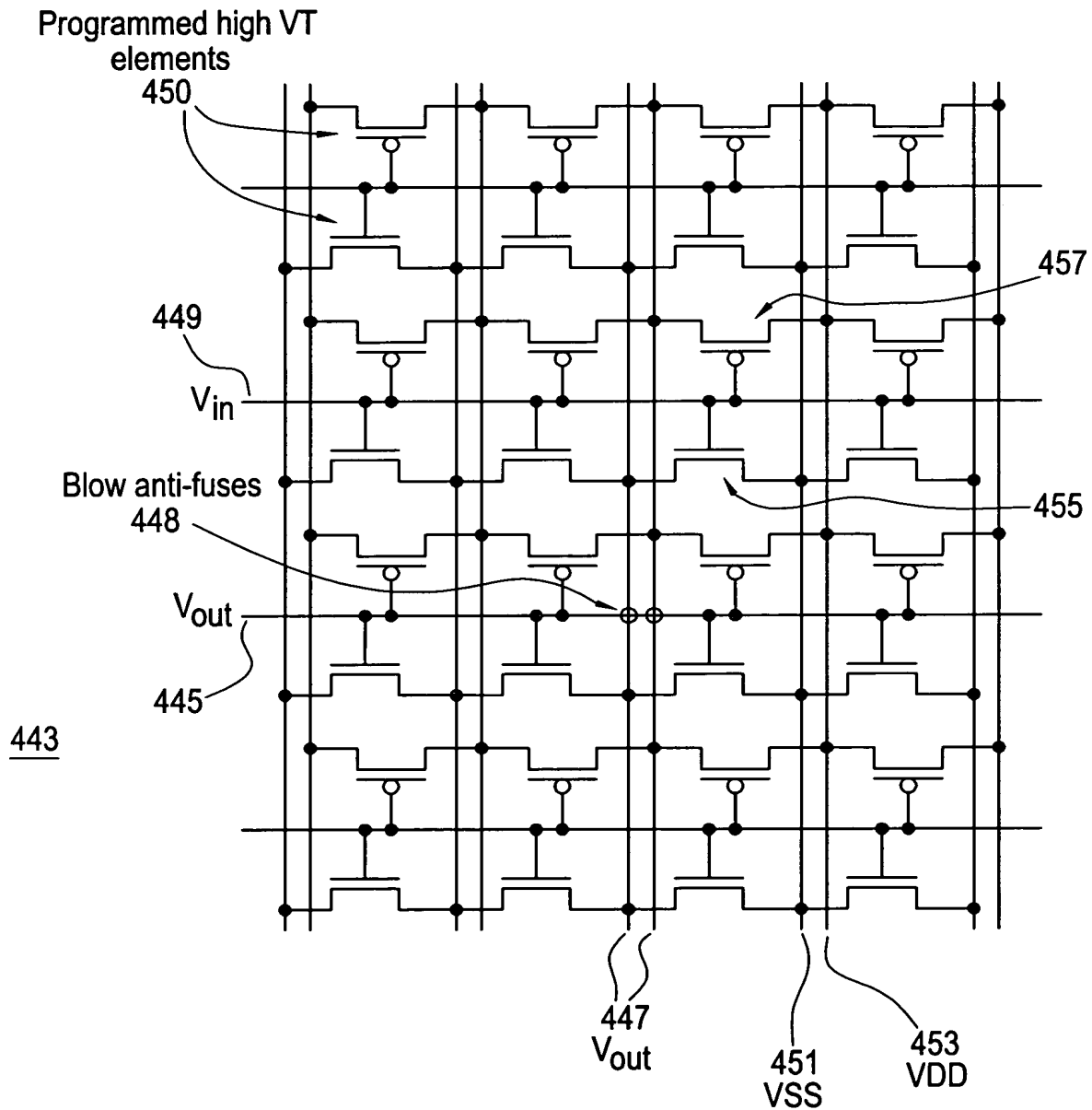


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FIG. 13





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FIG. 14

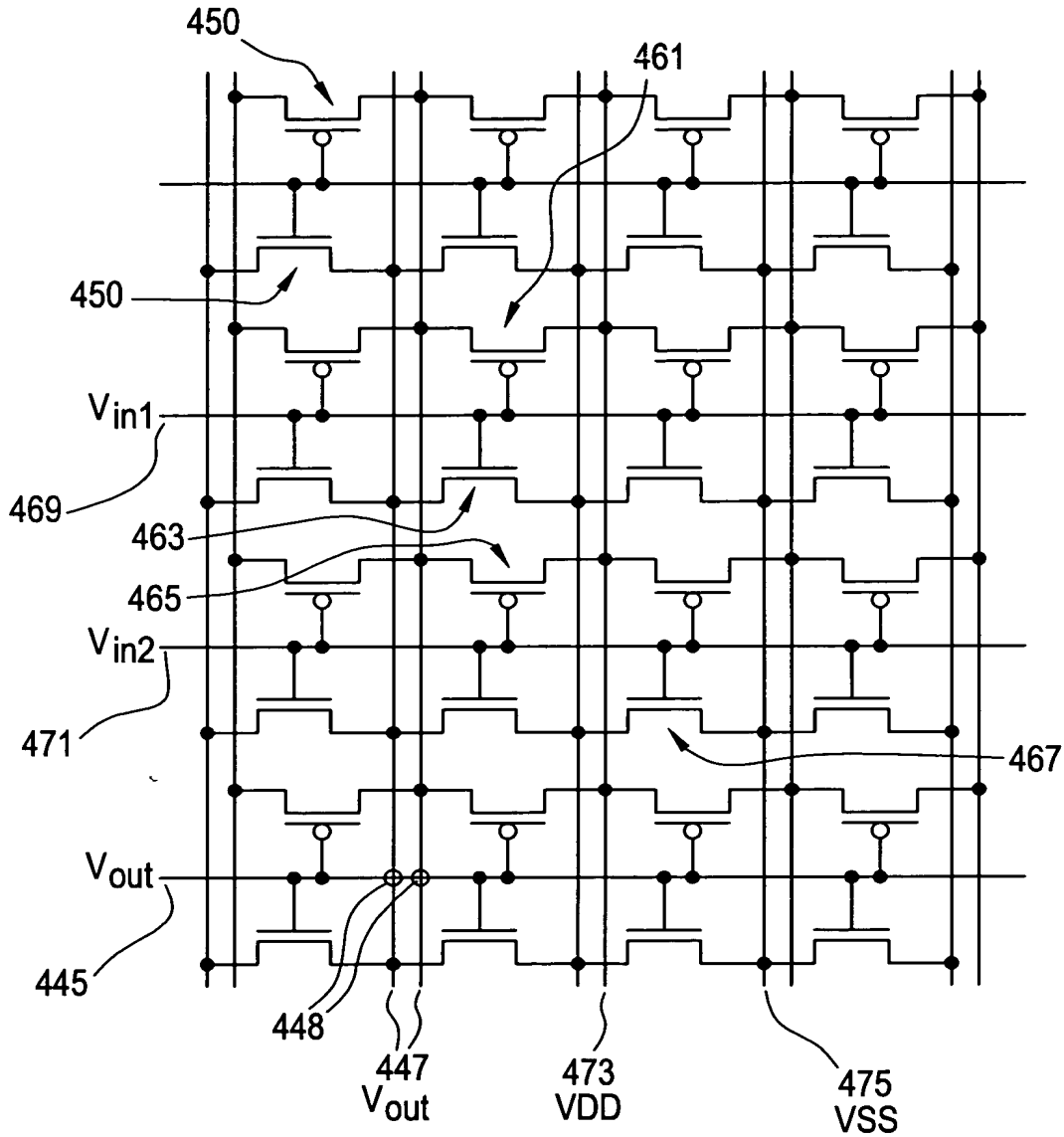


FIG. 15

